

Image

2823



DOCKET: CU-2636

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

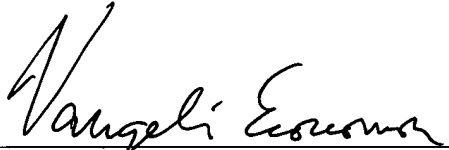
In re Application of: Sang Ick LEE et al.]
Serial No.: 09/994,284]
Filed: 26 November 2001]
For: METHOD OF FORMING METAL]
GATE IN SEMICONDUCTOR]
DEVICE]

Group Art Unit: 2823

Examiner: Pham, Thanh V.

Certification under 37 C.F.R. §1.8(a)

I hereby certify that this paper (along with any paper referred to as being attached or enclosed) is being deposited with The United States Postal Service with sufficient postage as first class mail in an envelope addressed to Commissioner for Patents, on April 2, 2004.


Vangelis Economou - Reg. No. 32,341

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

PRELIMINARY AMENDMENT

Sir:

Prior to examination on the merits of the above-identified application, in which a request for continued examination was submitted on February 7, 2004, Applicants submit the following Preliminary Amendment to the claims. Please consider the following claim amendments and remarks in the above-identified application.

AMENDMENTS TO THE CLAIMS:

This listing of claims will replace all prior versions, and listings, of claims in this application: